

# isc Silicon PNP Darlington Power Transistor

2SB1556

#### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
- : V<sub>(BR)CEO</sub>= -140V(Min)
- · High DC Current Gain-
  - : h<sub>FE</sub>= 5000(Min)@I<sub>C</sub>= -7A
- Complement to Type 2SD2385
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

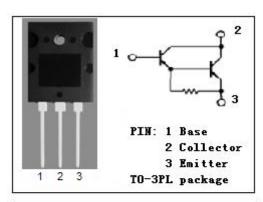
## **APPLICATIONS**

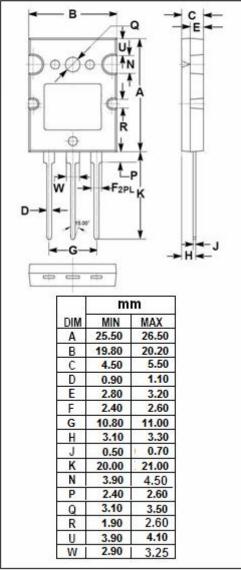


• Designed for power amplifier applications

## ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-140	V	
Vceo	Collector-Emitter Voltage	-140	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
Ic	Collector Current-Continuous -8		А	
I <sub>B</sub>	Base Current-Continuous	-0.1	А	
Pc	Collector Power Dissipation @ Tc=25℃		W	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range		°C	







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

-0 -0	. 0 = 0 a = 0 apatient							
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -50mA ; I <sub>B</sub> = 0	-140			V		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -7A; I <sub>B</sub> = -7mA			-2.5	V		
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -7A ; V <sub>CE</sub> = -5V			-3.0	V		
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -140V ; I <sub>E</sub> =0			-5	μА		
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -7A ; V <sub>CE</sub> = -5V	5000		30000			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -12A ; V <sub>CE</sub> = -5V	2000					
Сов	Output Capacitance	I <sub>E</sub> =0 ; V <sub>CB</sub> = -10V;f <sub>test</sub> = 1.0MHz		170		pF		
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> =-1A; V <sub>CE</sub> = -5V		30		MHz		

## ♦ h<sub>FE-1</sub> Classifications

Α	В	С
5000-12000	9000-18000	15000-30000

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